






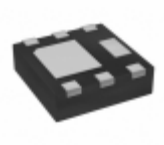


	DMT6004LPS-13	
	Hersteller-Teilenummer:	DMT6004LPS-13
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET N-CH 60V 22A
	Datenblätter:	 DMT6004LPS-13.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 16548 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	DMT6004LPS-13
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CH 60V 22A
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	16548 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	PowerDI5060-8
Verlustleistung (max)	2.1W (Ta), 105W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	22A (Ta), 90A (Tc)
Rds On (Max) @ Id, Vgs	2.8 mOhm @ 25A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	96.3nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4515pF @ 30V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































DMT6004LPS-13 ist neu im Original, Suche DMT6004LPS-13 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMT6004LPS-13 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMT6004LPS-13: Info@Y-IC.com

Sie können auch interessiert sein:

 DMT6004SPS Diodes Incorporated DMT6004SPS DIODES	 DMT4P22K-F Cornell Dubilier Electronics CAP FILM 0.22UF 10% 400VDC RAD	 DMT4S1K-F Cornell Dubilier Electronics CAP FILM 10000PF 10% 400VDC RAD	 DMT6005LCT Diodes Incorporated MOSFET NCH 60V 100A TO220AB
 DMT6004SCT Diodes Incorporated MOSFET N-CH 60V 100A TO220-3	 DMT5015LDF-7 Diodes Incorporated MOSFET N-CH 50V 9.1A 6DFN	 DMT6002LPS-13 Diodes Incorporated MOSFET N-CH 60V 100A POWERDI5060	 DMT6005LPS Diodes Incorporated DMT6005LPS DIODES

heiße Teile

Mehr

 DMT10H014LSS	 DMT10H015LK3-13	 DMT10H015LSS	 DMT10H015LSS-13	 DMT10H025SSS
 DMT3001LPS	 DMT3002LPS-13	 DMT3003LFG-13	 DMT3003LFG-7	 DMT3004LFG-13
 DMT3004LPS-13	 DMT3006LFG-13	 DMT3006LFV	 DMT3006LPS-13	 DMT3009LDT
 DMT3009LDT-13	 DMT3009LDT-7	 DMT3009LFVW	 DMT3009LFVW-13	 DMT3009LFVW-7
 DMT3020LPS	 DMT3020LSD	 DMT32M5LPS	 DMT4011LFG-7	 DMT40M9LPS-13
 DMT6004SPS	 DMT6004SPS-13	 DMT6005LPS	 DMT6005LPS-13	 DMT6005LSS
 DMT6008LFG	 DMT6008LFG-7	 DMT6009LCT	 DMT6009LFG	 DMT6009LFG-13
 DMT6009LK3	 DMT6009LPS	 DMT6009LPS-13	 DMT6009LSS	 DMT6010LFG
 DMT6010LFG-13	 DMT6010LFG-7	 DMT6010LPS-13	 DMT6010LSS	 DMT6010LSS-13
 DMT6010SCT	 DMT6015LFV	 DMT6015LFV-13	 DMT6015LFV-7	 DMT6015LPS-13

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